Supplementary Data

Study of Anisotropic Thermal conductivity in Textured

Thermoelectric Alloys by Raman Spectra

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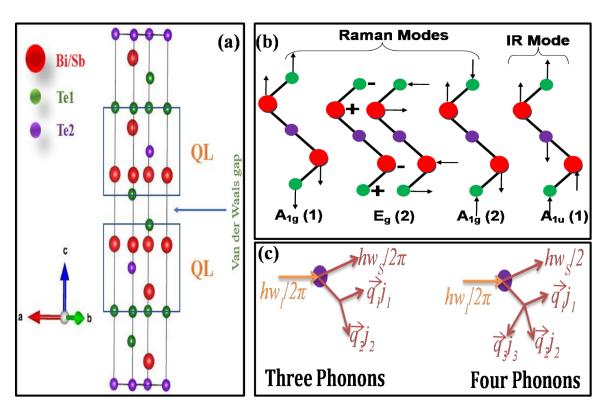


Figure S1

Fig. S1. (a) Crystal structure of Bi_2Te_3/Sb_2Te_3 , (b) Schematic representation of Raman active modes, and (c) Schematic representation of the three-phonon and the four phonon decay processes.



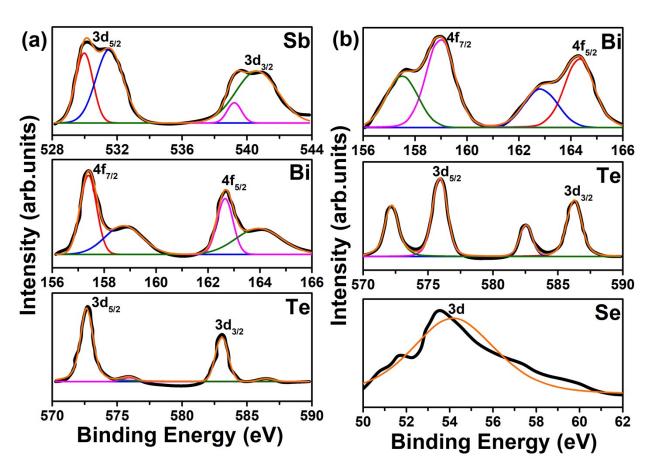


Fig. S2. XPS spectra of (a) p-type SBT (Sb 3d, Bi 4f, & Te 3d) and (b) n-type BTS (Bi 4f, Te 3d,

& Se 3*d*).



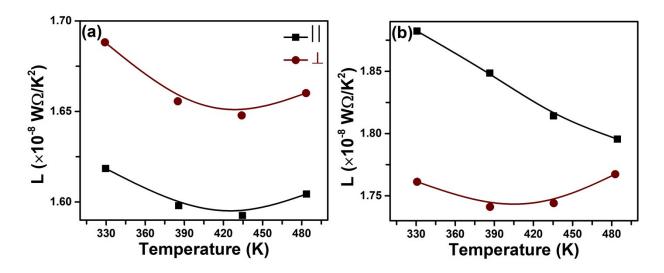


Fig. S3. Temperature dependent Lorenz number of **(a)** *p*-type SBT and **(b)** *n*-type BTS.

Figure S4

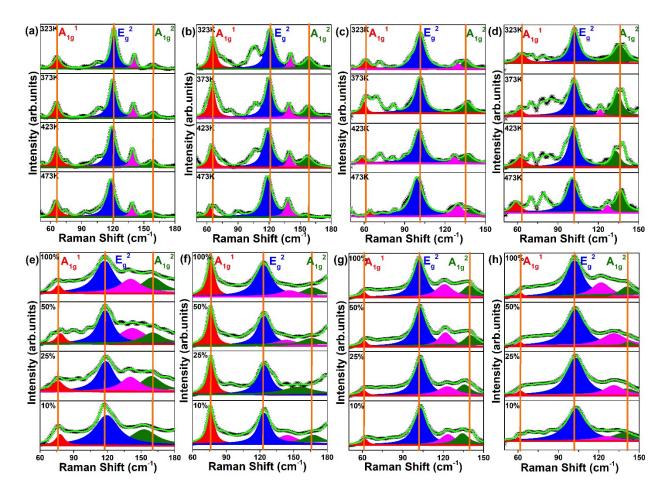


Fig. S4. Temperature dependent Raman spectra (a) Parallel direction, & (b) Perpendicular direction to the pressing axis; Laser power dependent (c) Parallel direction, & (d) Perpendicular direction to the pressing axis of *p*-type SBT; and Temperature dependent Raman spectra (e)
Parallel direction, & (f) Perpendicular direction to the pressing axis; Laser power dependent (g)
Parallel direction, & (h) Perpendicular direction to the pressing axis of *n*-type BTS.

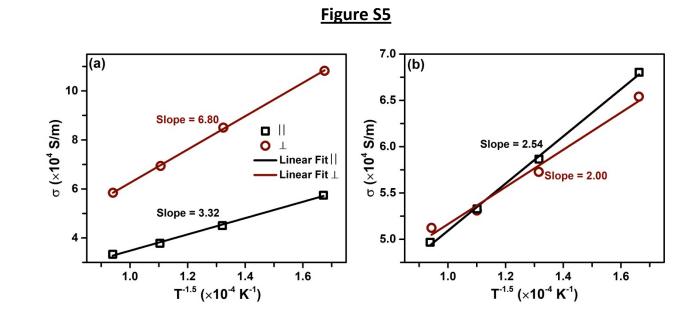


Fig. S5. Linear plot between σ and T^{-1.5} of **(a)** *p*-type SBT and **(b)** *n*-type BTS.



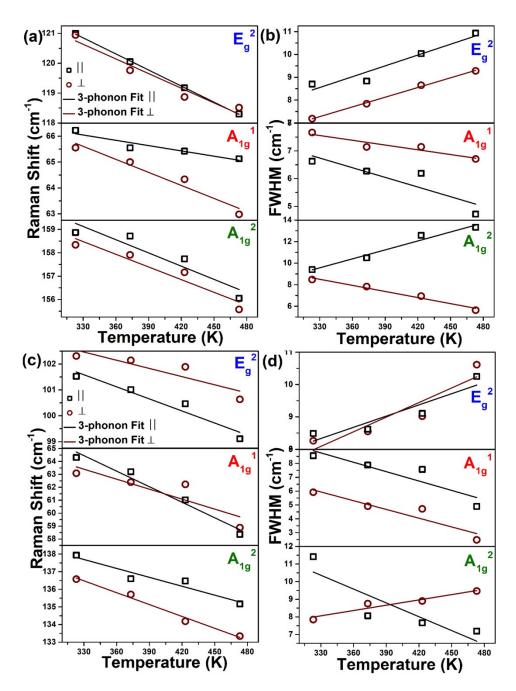


Fig. S6. Temperature dependent **(a)** Raman peak positions, & **(b)** FWHM of *p*-type SBT; and Temperature dependent **(c)** Raman peak positions, & **(d)** FWHM of *n*-type BTS.



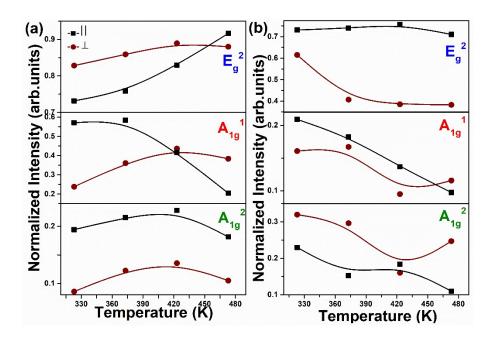


Fig. S7. Temperature dependent mode wise intensity of (a) *p*-type SBT, and (b) *n*-type BTS.

<u>Table S1</u>

Table S1. Raman active peaks of *p*-type SBT and *n*-type BTS in both directions: parallel and perpendicular to the pressing axis.

	<i>p</i> -type SBT		<i>n</i> -type BTS	
	Parallel	Perpendicular	Parallel	Perpendicular
	(11)	(上)	(11)	(土)
E_g^2	~117. 69	~123.14	~102.05	~101.98
A _{1g} ¹	~76.35	~76.07	~61.34	~61.92
A_{1g}^2	~160.33	~166.65	~139.33	~141.02